L Number	Hits	Search Text	DB	Time stamp
-	4	(("6410380") or ("5970340")).PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/23 16:47
-	506	@ad<=19970624 and (257/301).ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/23 16:48
-	240	@ad<=19970624 and (257/303).ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/23 16:49
-	287	@ad<=19970624 and (257/304).ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/23 16:49
-	258	@ad<=19970624 and (257/305).ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/23 16:49
-	761	@ad<=19970624 and (257/306).ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/23 17:49
-	113	@ad<=19970624 and (257/307).ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/23 16:50
-	167	@ad<=19970624 and (257/308).ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/23 16:50
-	238	@ad<=19970624 and (257/309).ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/23 16:50
-	583	@ad<=19970624 and (438/253).ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/23 16:51
-	2634	@ad<=19970624 and (438/396).ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/23 16:51
-	171	@ad<=19970624 and (438/254).ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/23 16:52
-	104	@ad<=19970624 and (438/255).ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/23 16:52
-	23	@ad<=19970624 and (438/256).ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/23 16:52

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-	134	@ad<=19970624 and (438/243-244).ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/23 16:53
-	10	(("5028990") or ("6107138") or ("5494841") or ("5739068") or ("5634974")).PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/23 17:00
-	384	@ad<=19970624 and (257/306).ccls. and 'DRAM'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/23 17:09
-	364	@ad<=19970624 and (257/306).ccls. and 'DRAM' and 'capacitor'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/23 17:09
-	340	@ad<=19970624 and (257/306).ccls. and 'DRAM' same 'capacitor'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/23 17:13
-	199	@ad<=19970624 and 'trench capacitor' with 'contact'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/23 17:35
-	124	@ad<=19970624 and 'stack capacitor' with 'contact'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/23 17:35
-	501	@ad<=19970624 and (257/306).ccls. and 'memory' same 'cell'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/23 17:50
-	262	@ad<=19970624 and (257/306).ccls. and 'dynamic' same 'memory' same 'cell'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/23 17:52

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